



# 100V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

#### **Product Summary**

BVDSS	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX T <sub>C</sub> = +25°C		
	32mΩ @ V <sub>GS</sub> = 10V	17A		
100V	50mΩ @ V <sub>GS</sub> = 4.5V	13A		

### **Description**

This MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

## Applications

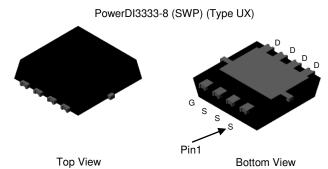
- Backlighting
- Power Management Functions
- DC-DC Converters

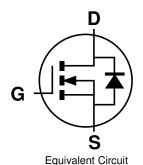
# **Features and Benefits**

- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.072 grams (Approximate)





# Ordering Information (Note 4)

Part Number	Case	Packaging
DMT10H032LFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000/Tape and Reel
DMT10H032LFVW-13	PowerDI3333-8 (SWP) (Type UX)	3,000/Tape and Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**





## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	100	V	
Gate-Source Voltage	Vgss	±20	V	
	Tc = +25°C	lo	17	A
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	Tc = +70°C		13	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	68	Α	
Maximum Continuous Body Diode Forward Current (Note 7)	Is	17	Α	
Pulsed Body Diode Forward Current (Note 8)	lsм	68	Α	
Avalanche Current, L = 0.3mH (Note 8)	las	13	Α	
Avalanche Energy, L = 0.3mH (Note 8)	Eas	25.3	mJ	

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0</sub> JA	92	°C/W
Total Power Dissipation (Note 6)		PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 6)  Steady State		R <sub>θ</sub> ЈА	49	°C/W
Thermal Resistance, Junction to Case (Note 7)		Rejc	8.9	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

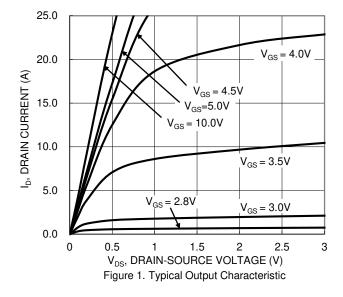
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

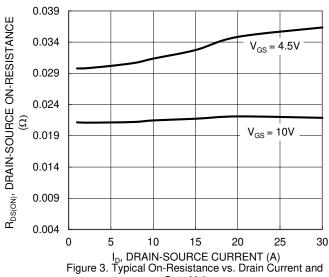
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BVDSS	100	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.3	l	2.5	٧	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D		22	32	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 10A	
Static Drain-Source On-nesistance	RDS(ON)	_	30	50	11122	$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	$V_{ extsf{SD}}$	-	0.8	1	V	V <sub>G</sub> S = 0V, I <sub>S</sub> = 6A	
DYNAMIC CHARACTERISTICS (Note 10)					•		
Input Capacitance	Ciss	I	683	_	рF		
Output Capacitance	Coss		165	_	рF	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V, -f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	6.9	_	pF	11 = 11VIDZ	
Gate Resistance	Rg	_	1.2	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	6.3	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	11.9	_	nC	501/ 1 04	
Gate-Source Charge	Qgs		2.0	_	nC	VDS = 50V, ID = 6A	
Gate-Drain Charge	Q <sub>gd</sub>		3.1	_	nC		
Turn-On Delay Time	tD(ON)		4.1	_	ns	$\begin{aligned} V_{DS} &= 50 \text{V}, \ R_L = 5.85 \Omega \\ V_{GS} &= 10 \text{V}, \ R_g = 3 \Omega \end{aligned}$	
Turn-On Rise Time	tR		4.5	_	ns		
Turn-Off Delay Time	tD(OFF)		12.5	_	ns		
Turn-Off Fall Time	tr		9.3	_	ns		
Reverse Recovery Time	t <sub>RR</sub>	_	31.5	_	ns		
Reverse Recovery Charge	Qrr	1	94.6	_	nC		

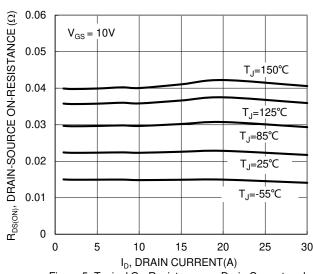
Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_{J} = +25$ °C.
- 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to product testing.









Gate Voltage

Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

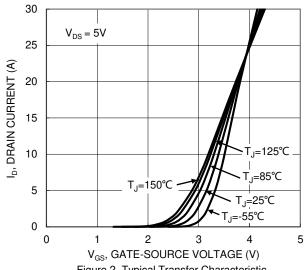


Figure 2. Typical Transfer Characteristic

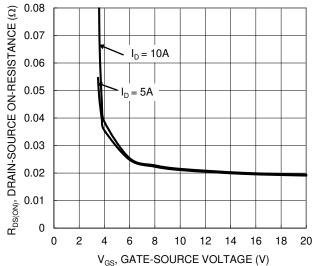


Figure 4. Typical Transfer Characteristic

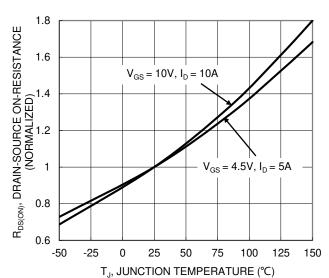
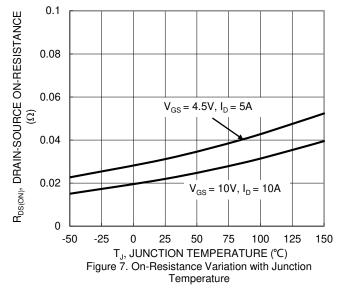
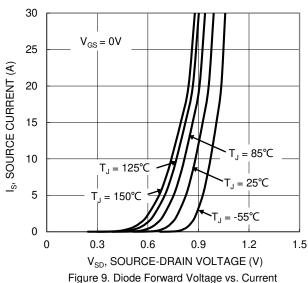
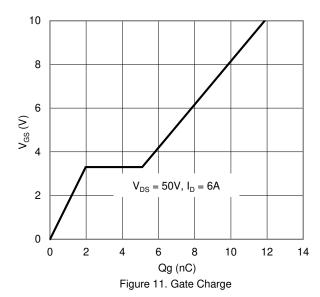


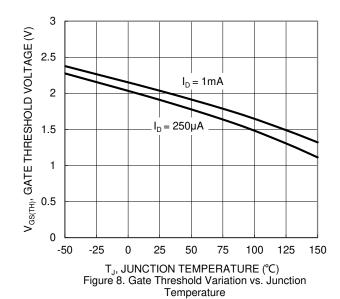
Figure 6. On-Resistance Variation with Junction Temperature

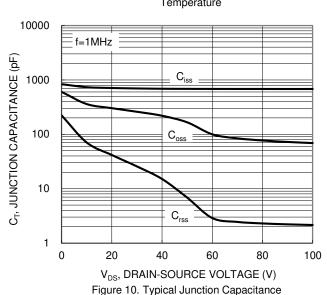


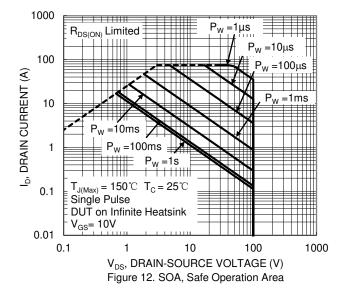














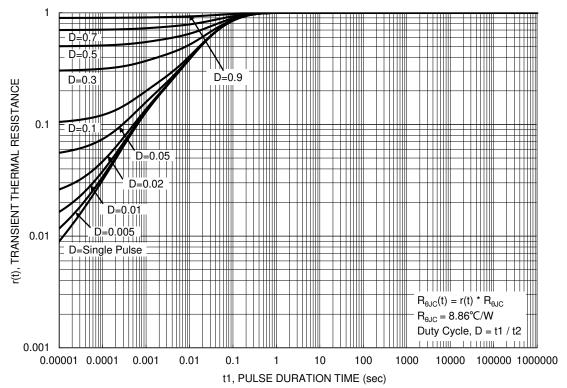


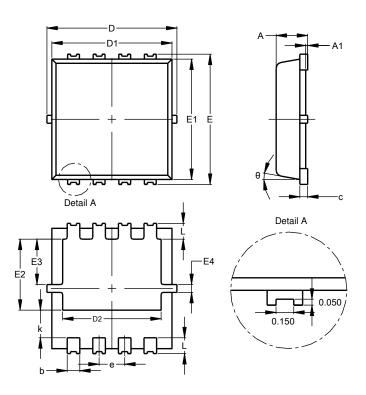
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)

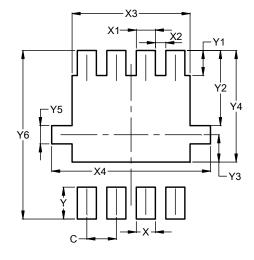


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min Max Ty		Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е			0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)	
C	0.650	
Х	0.420	
X1	0.420	
X2	0.230	
Х3	2.600	
X4	3.500	
Υ	0.700	
Y1	0.550	
Y2	1.650	
Y3	0.600	
Y4	2.450	
Y5	0.400	
Y6	3.700	



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